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Product data sheet

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NXP Semiconductors



NXP Semiconductors Product specification

General purpose PIN diode

BAP50-02

FEATURES

- Low diode capacitance
- Low diode forward resistance.

APPLICATIONS

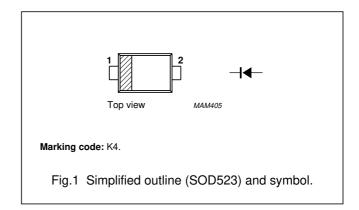
· General RF applications.

DESCRIPTION

General purpose PIN diode in a SOD523 small SMD plastic package.

PINNING

PIN	DESCRIPTION
1	cathode
2	anode



LIMITING VALUES

In accordance with the Absolute Maximum Rating System (IEC 60134).

SYMBOL	PARAMETER	CONDITIONS	MIN.	MAX.	UNIT
V_R	continuous reverse voltage		_	50	V
I _F	continuous forward current		_	50	mA
P _{tot}	total power dissipation	T _s = 90 °C	_	715	mW
T _{stg}	storage temperature		- 65	+150	°C
Tj	junction temperature		- 65	+150	°C

NXP Semiconductors Product specification

General purpose PIN diode

BAP50-02

ELECTRICAL CHARACTERISTICS

 $T_i = 25$ °C unless otherwise specified.

SYMBOL	PARAMETER	CONDITIONS	MIN.	TYP.	MAX.	UNIT
V _F	forward voltage	I _F = 50 mA	_	0.95	1.1	V
V _R	reverse voltage	I _R = 10 μA	50	_	_	V
I _R	reverse current	V _R = 50 V	_	_	100	nA
C _d	diode capacitance	V _R = 0; f = 1 MHz	_	0.4	_	pF
		$V_R = 1 V; f = 1 MHz$	_	0.3	0.55	pF
		V _R = 5 V; f = 1 MHz	_	0.22	0.35	pF
r_D	diode forward resistance	$I_F = 0.5 \text{ mA}$; $f = 100 \text{ MHz}$; note 1	_	25	40	Ω
		I _F = 1 mA; f = 100 MHz; note 1	_	14	25	Ω
		$I_F = 10 \text{ mA}$; $f = 100 \text{ MHz}$; note 1	_	3	5	Ω
s ₂₁ ²	isolation	V _R = 0; f = 900 MHz	_	20.4	_	dB
		V _R = 0; f = 1800 MHz	_	17.3	_	dB
		V _R = 0; f = 2450 MHz	_	15.5	_	dB
s ₂₁ ²	insertion loss	$I_F = 0.5 \text{ mA}$; $f = 900 \text{ MHz}$	_	1.74	_	dB
		$I_F = 0.5 \text{ mA}$; $f = 1800 \text{ MHz}$	_	1.79	_	dB
		I _F = 0.5 mA; f = 2450 MHz	_	1.88	_	dB
s ₂₁ ²	insertion loss	I _F = 1 mA; f = 900 MHz	_	1.03	_	dB
		$I_F = 1 \text{ mA}; f = 1800 \text{ MHz}$	_	1.09	_	dB
		I _F = 1 mA; f = 2450 MHz	_	1.15	_	dB
s ₂₁ ²	insertion loss	I _F = 10 mA; f = 900 MHz	_	0.26	_	dB
		I _F = 10 mA; f = 1800 MHz	_	0.32	_	dB
		I _F = 10 mA; f = 2450 MHz	_	0.34	_	dB
τ∟	charge carrier life time	when switched from $I_F = 10$ mA to $I_R = 6$ mA; $R_L = 100$ Ω ; measured at $I_R = 3$ mA	_	1.05	-	μs
L _S	series inductance	I _F = 100 mA; f = 100 MHz	_	0.6	_	nH

Note

THERMAL CHARACTERISTICS

SYMBOL	PARAMETER	VALUE	UNIT
R _{th j-s}	thermal resistance from junction to soldering point	85	K/W

^{1.} Guaranteed on AQL basis: inspection level S4, AQL 1.0.

General purpose PIN diode

BAP50-02

GRAPHICAL DATA

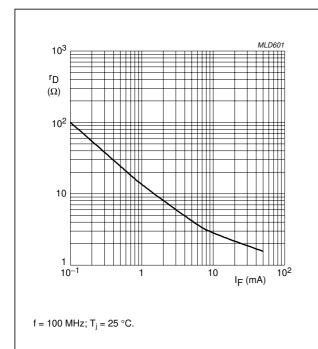
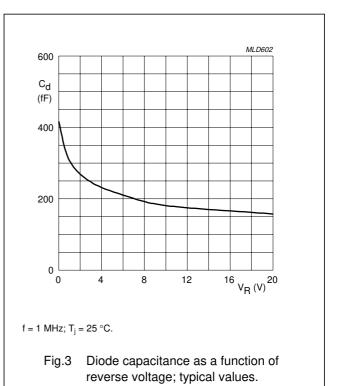
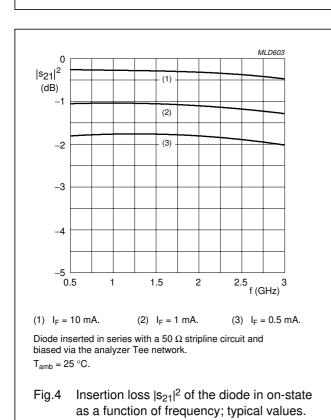
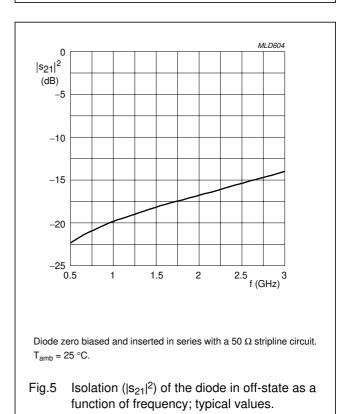


Fig.2 Forward resistance as a function of forward current; typical values.







NXP Semiconductors Product specification

General purpose PIN diode

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PACKAGE OUTLINE

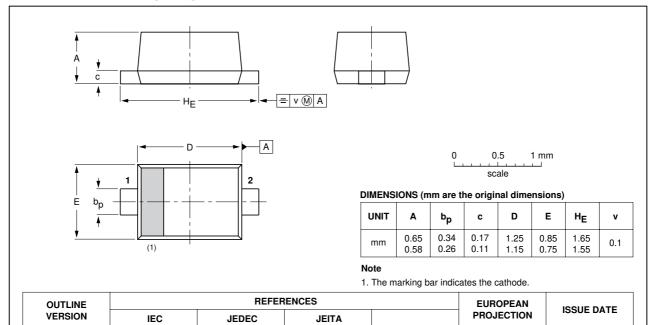
SOD523



SOD523

02-12-13

06-03-16



SC-79

NXP Semiconductors BAP50-02

General purpose PIN diode

Legal information

Data sheet status

Document status[1][2]	Product status[3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

- [1] Please consult the most recently issued document before initiating or completing a design.
- [2] The term 'short data sheet' is explained in section "Definitions"
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NXP Semiconductors BAP50-02

General purpose PIN diode

Revision history

Revision history

Document ID	Release date	Data sheet status	Change notice	Supersedes	
BAP50-02_N_2	20080103	Product data sheet	-	BAP50-02_1	
Modifications: • Package outline drawing on page 5 changed					
BAP50-02_1 (9397 750 08113)	20010417	Product specification	-	-	

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